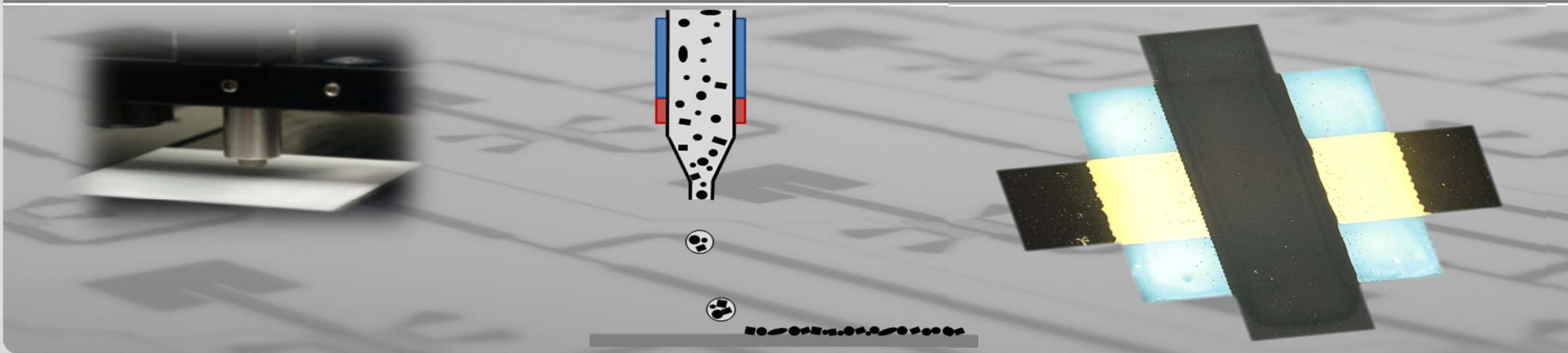


Polymerizable ceramic ink system for thin inkjet printed dielectric layers

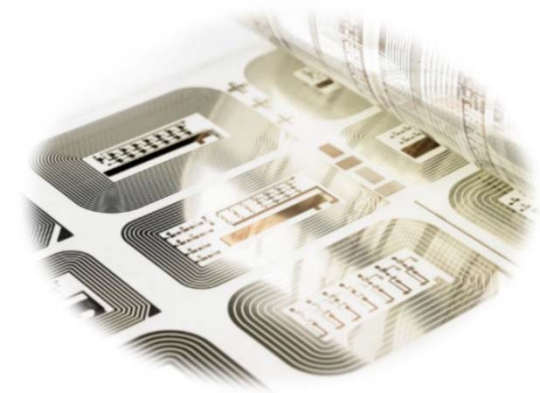
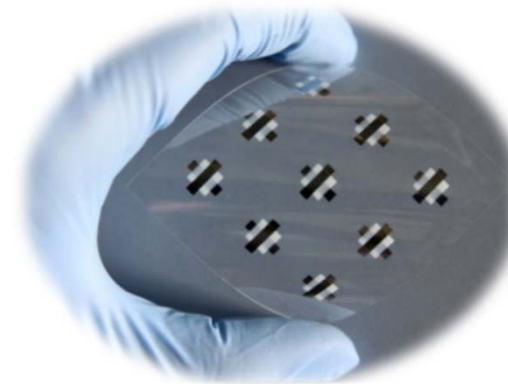
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Outline

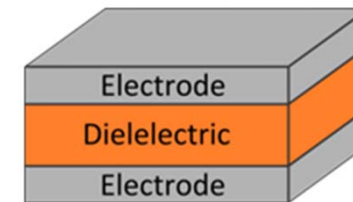
- 1) Capacitors
- 2) Printed capacitors: state of the art
- 3) Polymerizable ceramic ink system
 - Concept
 - Synthesis and ink development
 - Drying behavior
- 4) Dielectric properties of printed capacitors



Capacitors

■ Plate-capacitors

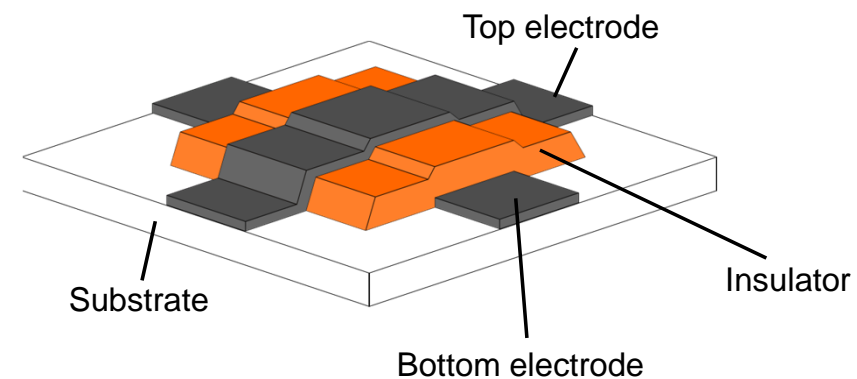
- Store electrical energy
- Simple fabrication
- Dielectric significantly influences properties
 - Ceramic materials
 - Plastic films



$$C = \epsilon_0 \epsilon_r \frac{A}{d}$$

■ Fully printed MIM-capacitors

- Electrodes: metal
 - Commercially Ag-Inks
- Dielectric: insulator
 - Ceramics/polymers
- Printable substrate
 - Ceramics/polymers



State of the art

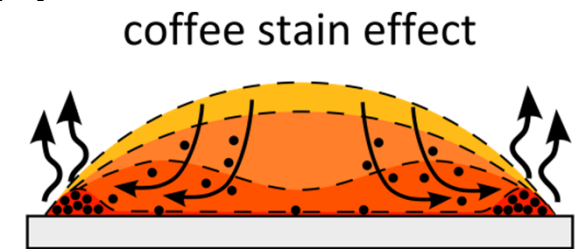
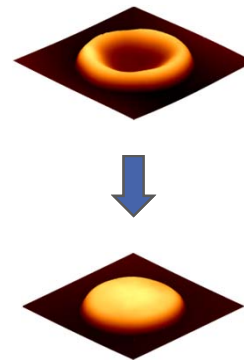
First Author	Dielectric material	Ratio [vol%] (cer./pol.)	Substrate	Layer thickness [μm]	Permittivity	Capacity [pF/mm ²]	Sintering Temperature [$^{\circ}\text{C}$]
Kaydanova ¹	BST		magnesia	0.42	1000	21100	1100
Graddage ²	PVP		PET	0.07	3.9	200	130
Mikolajek ³	BST + PMMA	66.6/33.3	PET	6	42	58	120

■ How to get thinner ceramic/polymer layers with high ϵ_r on PET ?

- Challenge: drying effects lead to short circuits

■ Avoiding coffee stain effect?

- Homogenous topographies
- No short circuits



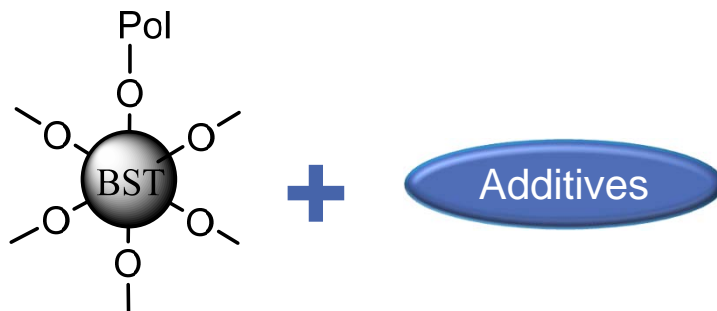
[1] T. Kaydanova et al., *Thin Solid Films* **2007**, 515, 3820.
 [2] N. Graddage et al., *Org. Electron.* **2016**, 29, 114.
 [3] M. Mikolajek, *Dissertation* **2018**.

New concept: polymerizable ceramic ink system

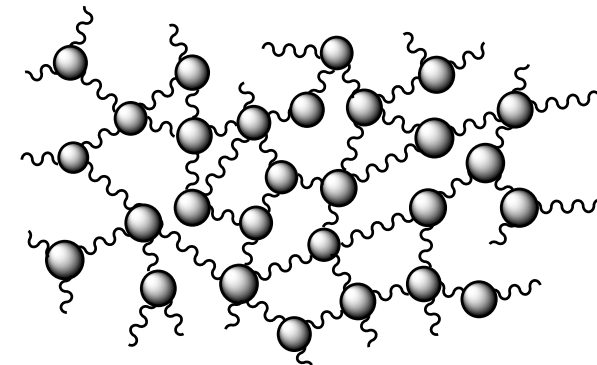
■ Surface modified ceramic particles

- Introducing of a polymerizable group
- Crosslinking during printing → strong rise of viscosity
- Very homogenous topographies even at low layer thicknesses

Polymerizable ceramic ink



Printed particle network structure

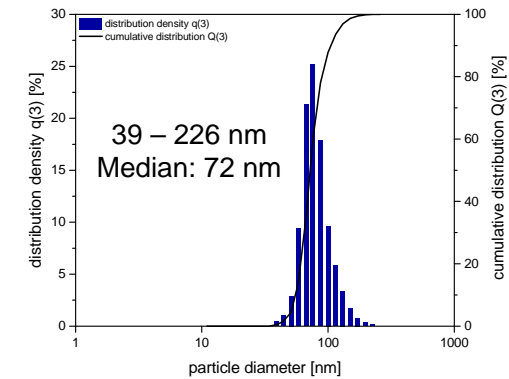


→ Control of coffee stain effect

Ceramic synthesis and surface modification

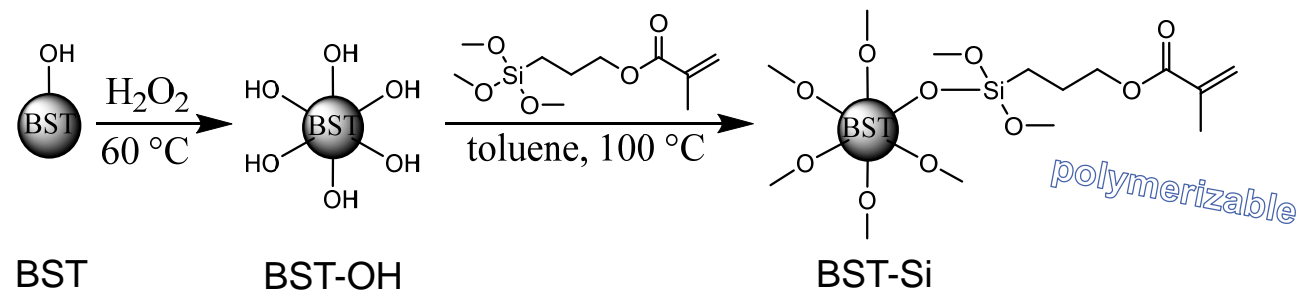
■ BST-Synthesis ($\text{Ba}_{0.6}\text{Sr}_{0.4}\text{TiO}_3$)

- Sol-Gel-Synthesis with acetic acid
- Spray drying
- Calcination at 1100 °C
- Milling and production of the dispersion in a stirred media mill



■ Reproducible 2-step surface modification

- Oxidation with H_2O_2
- Silanization with TMSPMA



→ Analytics: thermogravimetric analysis and XPS

Ink development

■ Ceramic powder dispersion

- After synthesis: powder gets dispersed in stirred media mill (deagglomeration)
 → BST-Si-Dispersion in butyldiglycol



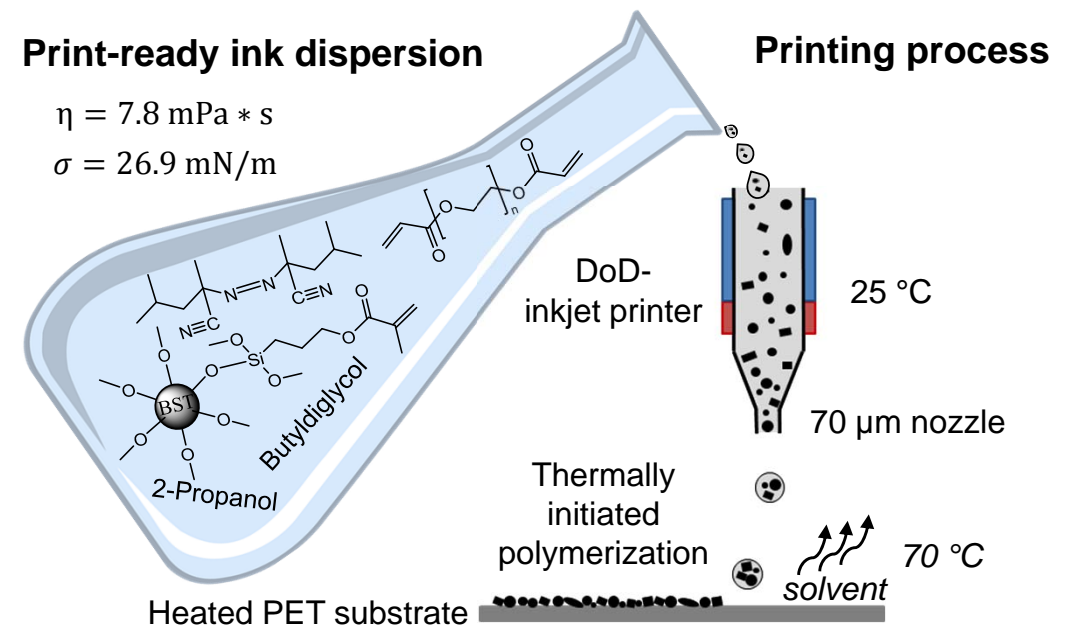
Additives

- + PEG-DA ($M_n:700$)
- + Thermal azo-initiator
- + IPA/BDG (dilution)

→ 10 vol% BST-Si/PEG-DA (50:50)

■ Polymerization?

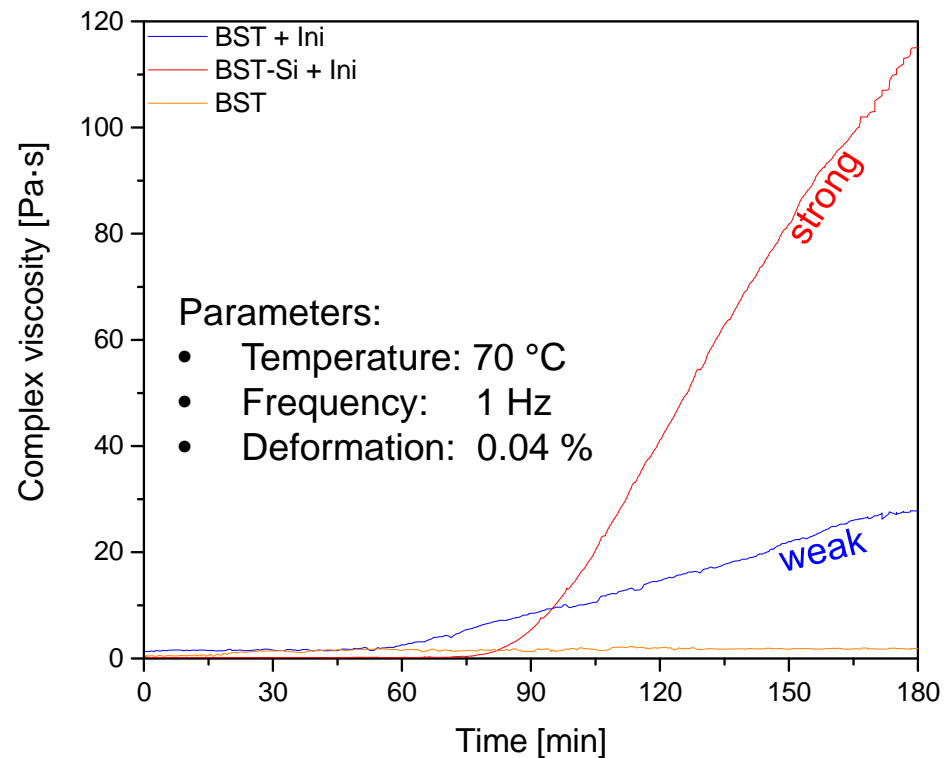
→ Oscillation measurement



Oscillation measurement

■ Surface modified vs. non-surface modified

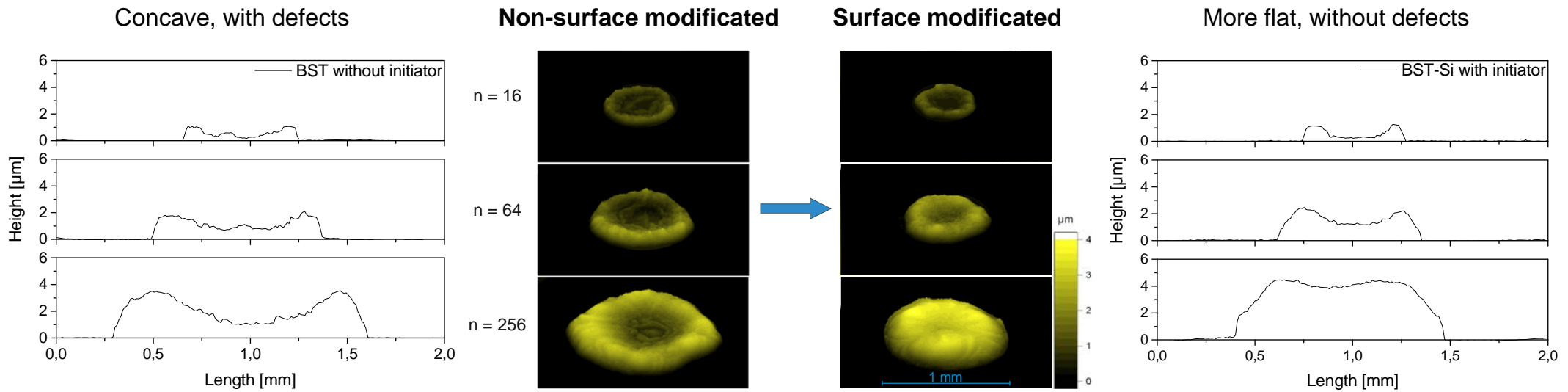
– BST-Si with initiator vs. BST with and without initiator



- **Strong:**
→ Particle network building
- **Weak:**
→ Polymerization of crosslinking agent
- **No polymerization**

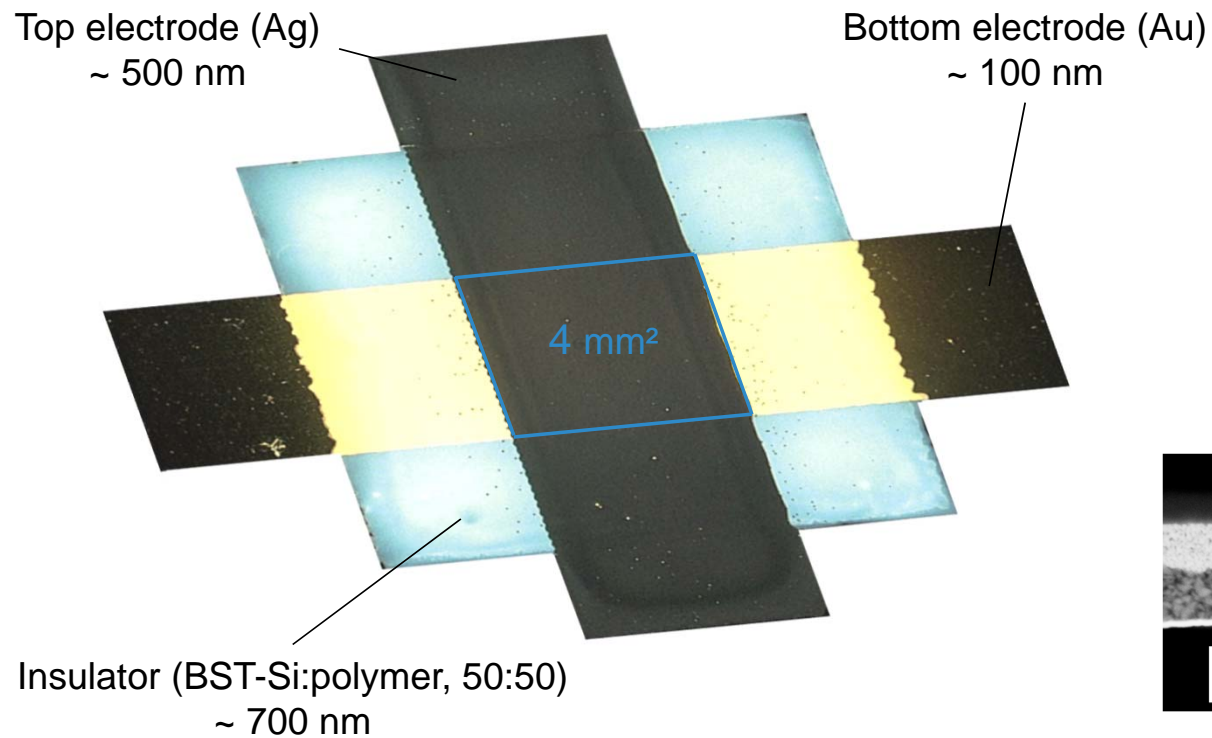
Drying behavior

3D-Topographies of printed drops (consisting of n droplets)



Printed capacitor

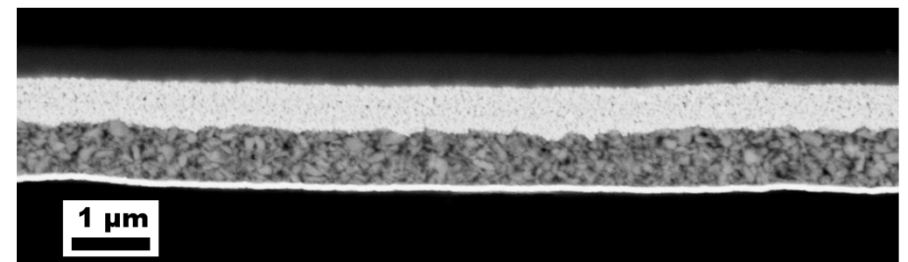
Microscope image of printed capacitor



Dielectric properties

- Effective area: 4 mm²
 - Capacity: ~ 2 nF
 - Permittivity: ~ 41
 - Q factor: ~ 17
- } @ 200 kHz

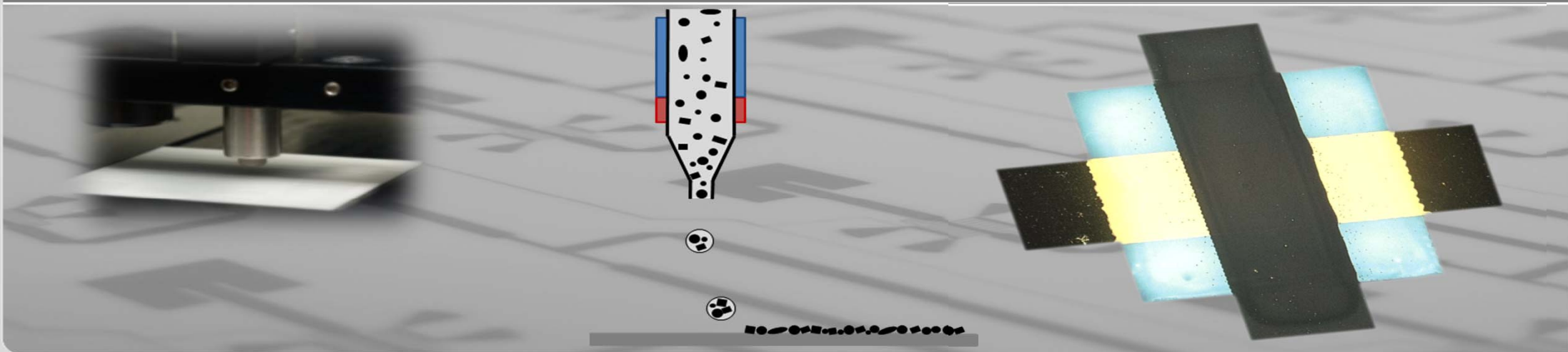
Cross sectional SEM-image



Polymerizable ceramic ink system for thin inkjet printed dielectric layers

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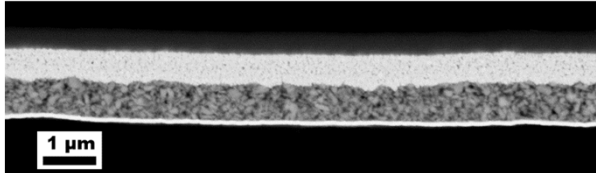


Variation of layer thickness

Options:

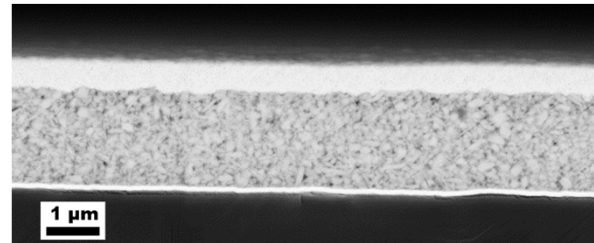
- Change drop distance
- Multilayer printing (90 μm drop distance):

1-layer: 700 nm



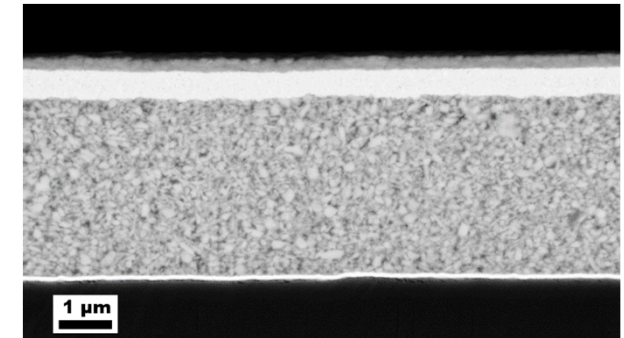
- Capacity: ~ 2080 pF
- Permittivity: ~ 41
- Q factor: ~ 17

2-layers: 1.8 μm



- Capacity: ~ 810 pF
- Permittivity: ~ 41
- Q factor: ~ 17

3-layers: 3.3 μm



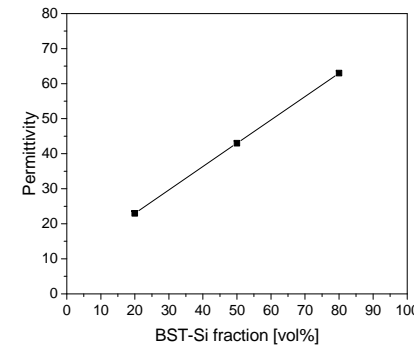
- Capacity: ~ 450 pF
- Permittivity: ~ 42
- Q factor: ~ 20

→ Permittivity remains the same ✓

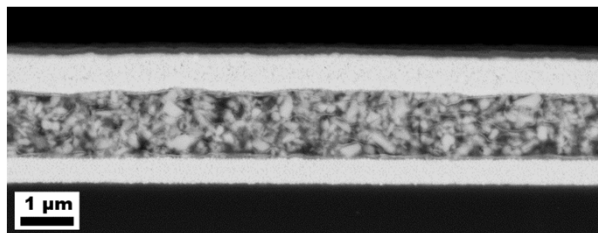
Variation of BST-Si:Polymer ratio

Overall solid content is 10 vol% for all inks

- Drop distance: 70 μm
- Bottom electrode: silver

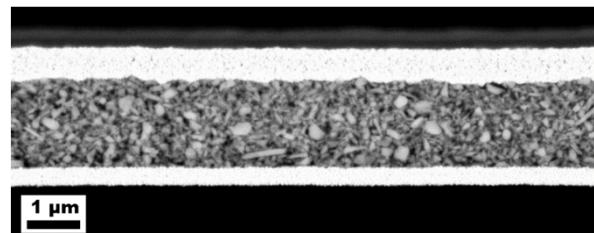


BST-Si:Polymer
20:80



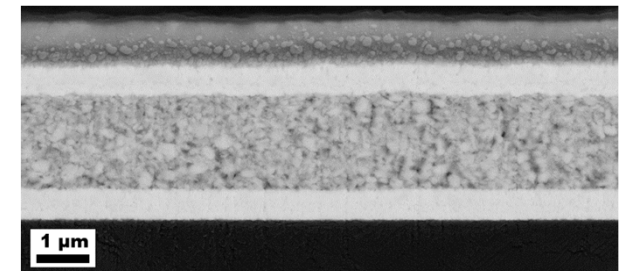
- Capacity: ~ 680 pF
- Permittivity: ~ 23
- Thickness: 1.2 μm
- Q factor: ~ 11

BST-Si:Polymer
50:50



- Capacity: ~ 950 pF
- Permittivity: ~ 43
- Thickness: 1.6 μm
- Q factor: ~ 14

BST-Si:Polymer
80:20



- Capacity: ~ 1240 pF
- Permittivity: ~ 63
- Thickness: 1.8 μm
- Q factor: ~ 14

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